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3-V TO 5.5-V MULTICHANNEL RS-232 LINE DRIVER/RECEIVER WITH ±15-kV ESD PROTECTION

FEATURES

- RS-232 Bus-Pin ESD Protection Exceeds ±15 kV Using Human-Body Model (HBM)
- Meets or Exceeds the Requirements of TIA/EIA-232-F and ITU v.28 Standards
- Operates With 3-V to 5.5-V V_{CC} Supply
- Operates Up To 250 kbit/s
- Two Drivers and Two Receivers
- Low Supply Current . . . 300 μA Typical
- External Capacitors . . . 4 × 0.1 μF
- Accepts 5-V Logic Input With 3.3-V Supply
- Alternative High-Speed Pin-Compatible Device (1 Mbit/s)
 - SNx5C3232

SUPPORTS DEFENSE, AEROSPACE, AND MEDICAL APPLICATIONS

- Controlled Baseline
- One Assembly/Test Site
- One Fabrication Site
- Available in Military (–55°C/125°C)
 Temperature Range⁽¹⁾
- Extended Product Life Cycle
- Extended Product-Change Notification
- Product Traceability
- (1) Additional temperature ranges are available contact factory

ORDERING INFORMATION(1)

T _A	PAC	KAGE ⁽²⁾	ORDERABLE PART NUMBER	TOP-SIDE MARKING
–55°C to 125°C	SSOP (DB)	Reel of 2000	MAX3232MDBREP	MB3232M
-55 C to 125 C	TSSOP(PW)	Reel of 2000	MAX3232MPWREP	IVIDSZSZIVI

- (1) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI website at www.ti.com.
- (2) Package drawings, thermal data, and symbolization are available at www.ti.com/packaging.

DESCRIPTION

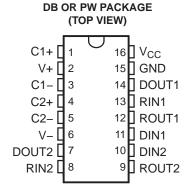
The MAX3232 device consists of two line drivers, two line receivers, and a dual charge-pump circuit with ± 15 -kV ESD protection pin to pin (serial-port connection pins, including GND). The device meets the requirements of TIA/EIA-232-F and provides the electrical interface between an asynchronous communication controller and the serial-port connector. The charge pump and four small external capacitors allow operation from a single 3-V to 5.5-V supply. The devices operate at data signaling rates up to 250 kbit/s and a maximum of 30-V/ μ s driver output slew rate.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

APPLICATIONS

 Battery-Powered Systems, PDAs, Notebooks, Laptops, Palmtop PCs, and Hand-Held Equipment

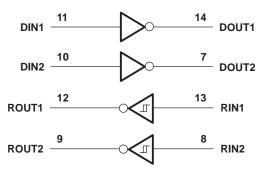




FUNCTION TABLE

EACH I	DRIVER	EACH RECEIVER							
INPUT DIN	OUTPUT DOUT	INPUT RIN	OUTPUT ROUT						
L	Н	L	Н						
Н	L	Н	L						
		Open	Н						
H = high level, L = low lev	H = high level, L = low level, Open = input disconnected or connected driver off								

LOGIC DIAGRAM (POSITIVE LOGIC)



ABSOLUTE MAXIMUM RATINGS

over operating free-air temperature range (unless otherwise noted)

			VALUE	UNIT			
V _{CC}	Supply voltage range ⁽¹⁾		-0.3 to 6	V			
V+	Positive output supply voltage range ⁽¹⁾	Positive output supply voltage range ⁽¹⁾					
V-	Negative output supply voltage range ⁽¹⁾	0.3 to -7	V				
V+ - V-	Supply voltage difference ⁽¹⁾		13	V			
V _I	Input voltage range	Drivers	-0.3 to 6	V			
		Receivers	-25 to 25	V			
.,	Output voltage range	Output voltage range Drivers					
Vo		Receivers	-0.3 to V _{CC} + 0.3	V			
θ_{JA}	Package thermal impedance ⁽²⁾	DB package	82	°C/W			
		PW package					
TJ	Operating virtual junction temperature	ı	150	°C			
T _{stg}	Storage temperature range		-65 to 150	°C			

⁽¹⁾ All voltages are with respect to network GND.

RECOMMENDED OPERATING CONDITIONS (see (1) and Figure 4)

				MIN	NOM	MAX	UNIT
	Supply voltage		V _{CC} = 3.3 V	3	3.3	3.6	V
Supply voltage			$V_{CC} = 5 V$	4.5	5	5.5	V
\/	Driver high level input voltege	DIN	$V_{CC} = 3.3 \text{ V}$	2			V
V_{IH}	Driver high-level input voltage	DIN	$V_{CC} = 5 V$	2.4			\ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \
V_{IL}	Driver low-level input voltage	DIN				8.0	V

(1) Test conditions are C1–C4 = 0.1 μ F at V_{CC} = 3.3 V ±0.3 V; C1 = 0.047 μ F, C2–C4 = 0.33 μ F at V_{CC} = 5 V ±0.5 V.

⁽²⁾ Maximum power dissipation is a function of $T_J(max)$, θ_{JA} , and T_A . The maximum allowable power dissipation at any allowable ambient temperature is $P_D = (T_J(max) - T_A)/\theta_{JA}$. Operating at the absolute maximum T_J of 150°C can affect reliability.



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RECOMMENDED OPERATING CONDITIONS (see and Figure 4) (continued)

				MIN	NOM	MAX	UNIT
V	Driver input voltage	DIN				5.5	1/
V _I	Receiver input voltage	-25		25	v		
T _A	Operating free-air temperature	MAX3232M		-55		125	°C

ELECTRICAL CHARACTERISTICS

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see (1) and Figure 4)

	PARAMETER	TEST CONDITIONS	MIN	TYP ⁽²⁾	MAX	UNIT
I _{CC}	Supply current	No load, V _{CC} = 3.3 V or 5 V		0.3	2	mA

Test conditions are C1–C4 = 0.1 μ F at V_{CC} = 3.3 V ±0.3 V; C1 = 0.047 μ F, C2–C4 = 0.33 μ F at V_{CC} = 5 V ±0.5 V. All typical values are at V_{CC} = 3.3 V or V_{CC} = 5 V, and T_A = 25°C.



DRIVER SECTION

ELECTRICAL CHARACTERISTICS

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see (1) and Figure 4)

	PARAMETER	TEST CONDIT	TONS	MIN	TYP ⁽²⁾	MAX	UNIT
V_{OH}	High-level output voltage	DOUT at $R_L = 3 \text{ k}\Omega$ to GND,	DIN = GND	5	5.4		٧
V_{OL}	Low-level output voltage	DOUT at $R_L = 3 \text{ k}\Omega$ to GND,	$DIN = V_{CC}$	- 5	-5.4		٧
I _{IH}	High-level input current	$V_I = V_{CC}$			±0.01	±1	μΑ
I _{IL}	Low-level input current	V _I at GND			±0.01	±1	μΑ
I _{OS} (3)	Short-circuit output current	V _{CC} = 3.6 V,	V _O = 0 V		.25	±60	mA
IOS (°)	Short-circuit output current	$V_{CC} = 5.5 \text{ V},$	$V_O = 0 V$		±35	±00	IIIA
r _o	Output resistance	V_{CC} , V+, and V- = 0 V,	$V_O = \pm 2 V$	300	10M		Ω

SWITCHING CHARACTERISTICS

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see (1) and Figure 4)

	PARAMETER	TEST COM	MIN	TYP ⁽²⁾	MAX	UNIT	
Maximum data rate		$ \begin{array}{lll} C_L = 1000 \; pF, & R_L = 3 \; k\Omega, \\ \text{One DOUT switching,} & \text{See Figure 1} \end{array} $		150	250		kbit/s
t _{sk(p)}	Pulse skew ⁽¹⁾	CL = 150 pF to 2500 pF	$R_L = 3 \text{ k}\Omega \text{ to 7 k}\Omega,$ See Figure 2		300		ns
SR(tr)	Slew rate, transition region (see	RL = $3 \text{ k}\Omega$ to $7 \text{ k}\Omega$,	C _L = 150 pF to 1000 pF	6		30	V/us
SK(II)	Figure 1)	$V_{CC} = 3.3 \text{ V}$	C _L = 150 pF to 2500 pF	4		30	ν/μδ

Short-circuit durations should be controlled to prevent exceeding the device absolute power dissipation ratings, and not more than one output should be shorted at a time.

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Test conditions are C1–C4 = 0.1 μ F at V_{CC} = 3.3 V ±0.3 V; C1 = 0.047 μ F, C2–C4 = 0.33 μ F at V_{CC} = 5 V ±0.5 V. All typical values are at V_{CC} = 3.3 V or V_{CC} = 5 V, and T_A = 25°C. Short-circuit durations should be controlled to prevent exceeding the device absolute power dissipation ratings, and not more than one output should be shorted at a time.

All typical values are at V_{CC} = 3.3 V or V_{CC} = 5 V, and T_A = 25°C.



RECEIVER SECTION

ELECTRICAL CHARACTERISTICS

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted (see (1) and Figure 4)

	PARAMETER	TEST CONDITIONS	MIN	TYP ⁽²⁾	MAX	UNIT	
V_{OH}	High-level output voltage	I _{OH} = -1 mA	V _{CC} -0.6	V _{CC} -0.1		V	
V_{OL}	Low-level output voltage	I _{OL} = 1.6 mA			0.4	V	
V	/ _{IT+} Positive-going input threshold voltage	V _{CC} = 3.3 V		1.5	2.4	V	
VIT+		V _{CC} = 5 V		1.8	2.4	V	
V	Negative gains input threehold voltage	V _{CC} = 3.3 V	0.6	1.2		W	
V_{IT-}	Negative-going input threshold voltage	V _{CC} = 5 V	0.8	1.5		V	
V _{hys}	Input hysteresis (V _{IT+} – V _{IT-})			0.3		V	
ri	Input resistance	V _I = ±3 V to ±25 V	3	5	8	kΩ	

- Test conditions are C1–C4 = 0.1 μ F at V_{CC} = 3.3 V ±0.3 V; C1 = 0.047 μ F, C2–C4 = 0.33 μ F at V_{CC} = 5 V ±0.5 V. All typical values are at V_{CC} = 3.3 V or V_{CC} = 5 V and T_A = 25°C.

SWITCHING CHARACTERISTICS

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted (see (1) and Figure 3)

	PARAMETER	TEST CONDITIONS	MIN	TYP ⁽²⁾	MAX	UNIT
t _{PLH}	Propagation delay time, low- to high-level output	C 450 pF		300		ns
t _{PHL}	Propagation delay time, high- to low-level output	$C_L = 150 \text{ pF}$		300		ns
t _{sk(p)}	Pulse skew ⁽³⁾			300		ns

- Test conditions are C1–C4 = 0.1 μ F at V_{CC} = 3.3 V ±0.3 V; C1 = 0.047 μ F, C2–C4 = 0.33 μ F at V_{CC} = 5 V ±0.5 V.
- All typical values are at $V_{CC} = 3.3 \text{ V}$ or $V_{CC} = 5 \text{ V}$ and $T_A = 25 ^{\circ}\text{C}$.
- Pulse skew is defined as |t_{PLH} t_{PHL}| of each channel of the same device.

PARMETER MEASUREMENT INFORMATION

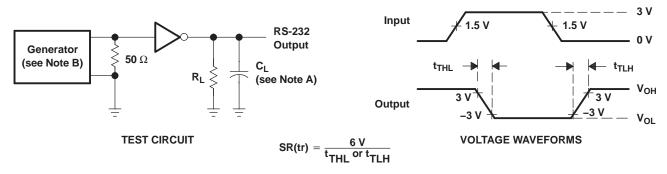
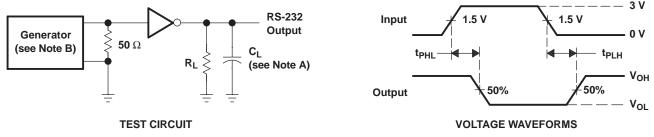


Figure 1. Driver Slew Rate



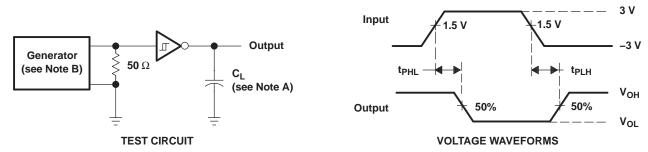
- C_L includes probe and jig capacitance.
- The pulse generator has the following characteristics: $Z_0 = 50 \Omega$, 50% duty cycle, tr ≤ 10 ns, tf ≤ 10 ns.

Figure 2. Driver Pulse Skew

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PARMETER MEASUREMENT INFORMATION (continued)

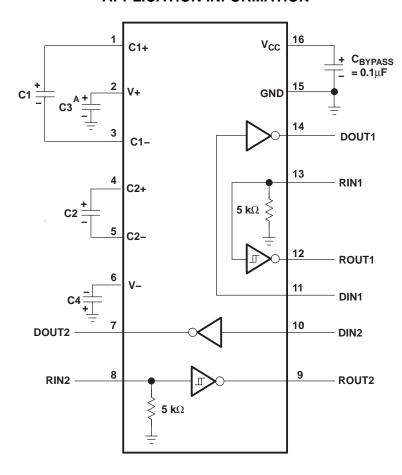


- A. C_L includes probe and jig capacitance.
- B. The pulse generator has the following characteristics: Z_0 = 50 Ω , 50% duty cycle, tr \leq 10 ns, tf \leq 10 ns.

Figure 3. Receiver Propagation Delay Times



APPLICATION INFORMATION



V_{CC} vs CAPACITOR VALUES

V _{CC}	C1	C2, C3, C4
$\begin{array}{c} \textbf{3.3 V} \pm \textbf{0.3 V} \\ \textbf{5 V} \pm \textbf{0.5 V} \\ \textbf{3 V to 5.5 V} \end{array}$	0.1 μF 0.047 μF 0.1 μF	0.1 μF 0.33 μF 0.47 μF

- A. C3 can be connected to V_{CC} or GND.
- B. Resistor values shown are nominal.
- C. Nonpolarized ceramic capacitros are acceptable. If polarized tantalum or electrolytic capacitors are used, they should be connected as shown.

Figure 4. Typical Operating Circuit and Capacitor Values



PACKAGE OPTION ADDENDUM



10-Dec-2020

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
MAX3232MDBREP	ACTIVE	SSOP	DB	16	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	MB3232M	Samples
MAX3232MPWREP	ACTIVE	TSSOP	PW	16	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	MB3232M	Samples
V62/06623-01XE	ACTIVE	SSOP	DB	16	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	MB3232M	Samples
V62/06623-01YE	ACTIVE	TSSOP	PW	16	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	MB3232M	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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PACKAGE OPTION ADDENDUM

10-Dec-2020

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OTHER QUALIFIED VERSIONS OF MAX3232-EP:

NOTE: Qualified Version Definitions:

• Catalog - TI's standard catalog product

PACKAGE MATERIALS INFORMATION

www.ti.com 3-Jun-2022

TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
MAX3232MDBREP	SSOP	DB	16	2000	330.0	16.4	8.35	6.6	2.5	12.0	16.0	Q1
MAX3232MPWREP	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1

PACKAGE MATERIALS INFORMATION

www.ti.com 3-Jun-2022



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
MAX3232MDBREP	SSOP	DB	16	2000	367.0	367.0	38.0
MAX3232MPWREP	TSSOP	PW	16	2000	356.0	356.0	35.0





NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153.





NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.





NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.







NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
 4. Reference JEDEC registration MO-150.





NOTES: (continued)

- 5. Publication IPC-7351 may have alternate designs.
- 6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.





NOTES: (continued)

- 7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 8. Board assembly site may have different recommendations for stencil design.



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